L Number	Hits	Search Text	DB	Time stamp
7	2	("5554870").PN.	USPAT;	2004/10/18
		_	US-PGPUB;	13:33
		,	EPO; JPO; DERWENT;	
	:		IBM TDB	
8	15	(("5324673") or ("5612230") or	USPAT;	2004/10/18
		("6150688") or ("5574299") or ("5483094") or ("5460994") or ("5698869") or	US-PGPUB; EPO; JPO;	13:47
		("6433382")).PN.	DERWENT;	
			IBM_TDB	
9	21	(("6159852") or ("6448129") or ("6458699") or ("6509239") or ("6392271")	USPAT; US-PGPUB;	2004/10/18
		or ("5578850") or ("5753947") or	EPO; JPO;	13:48
		("6433382") or ("6018176") or ("5547889")	DERWENT;	
		or ("5460994")).PN.	IBM_TDB	
10	1489	(257/316).ccls. and @ad<=20010323	USPAT; US-PGPUB;	2004/10/18
			EPO; JPO;	14.20
			DERWENT;	
11	485	/257/202\ aala	IBM_TDB	2004/10/10
11	485	(257/303).ccls. and @ad<=20010323	USPAT; US-PGPUB;	2004/10/18 14:21
			EPO; JPO;	
			DERWENT;	
12	319	(438/300).ccls. and @ad<=20010323	IBM_TDB USPAT;	2004/10/18
	3.23	(1000)	US-PGPUB;	14:23
			EPO; JPO;	
			DERWENT; IBM TDB	
13	155	(257/929).ccls. and @ad<=20010323	USPAT;	2004/10/18
			US-PGPUB;	14:23
			EPO; JPO; DERWENT;	
			IBM TDB	
14	884	(257/368).ccls. and @ad<=20010323	USPAT;	2004/10/18
	•		US-PGPUB; EPO; JPO;	14:25
			DERWENT;	
	5.0	(400 (000)	IBM_TDB	0004/10/10
16	51	(438/222).ccls. and @ad<=20010323	USPAT; US-PGPUB;	2004/10/18 14:31
			EPO; JPO;	
			DERWENT;	
17	78	(438/226).ccls. and @ad<=20010323	IBM_TDB USPAT;	2004/10/18
			US-PGPUB;	14:31
			EPO; JPO;	
			DERWENT; IBM TDB	
18	72	(438/341).ccls. and @ad<=20010323	USPAT;	2004/10/18
			US-PGPUB;	14:32
			EPO; JPO; DERWENT;	
			IBM_TDB	
19	212	(438/357).ccls. and @ad<=20010323	USPAT;	2004/10/18
			US-PGPUB; EPO; JPO;	14:33
			DERWENT;	
	10	//#5202601#\ on /#6201602#\ on	IBM_TDB	2002/06/25
-	10	(("5393681") or ("6391692") or ("5308782") or ("5998248") or	USPAT; US-PGPUB;	2003/06/25
		("6319782")).PN.	EPO; JPO;	
			DERWENT;	
_	162	257/929 and @ad<=20010323	IBM_TDB USPAT;	2003/06/24
			US-PGPUB;	14:45
			EPO; JPO;	
			DERWENT; IBM TDB	
	L		1 1011 100	

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-	542	438/300 and @ad<=20010323	USPAT; US-PGPUB;	2003/06/24
			EPO; JPO;	14.44
			DERWENT;	
	4	Rode-20010222 and Instinct working?	IBM_TDB USPAT;	2002/00/04
-	4	<pre>@ad<=20010323 and 'raised vertical lateral transistor'</pre>	USPAT; US-PGPUB;	2002/09/04
			EPO; JPO;	
			DERWENT;	
_	1	@ad<=20010323 and 'raised source and	IBM_TDB USPAT;	2002/09/04
	_	drain'	US-PGPUB;	15:26
			EPO; JPO;	
			DERWENT; IBM TDB	
_	1	@ad<=20010323 and 'epitaxial' and 'source	USPAT;	2002/09/04
İ		or drain'	US-PGPUB;	15:30
			EPO; JPO; DERWENT;	
			IBM TDB	
-	8	@ad<=20010323 and 'epitaxial' and 'source	USPAT;	2002/09/04
		and drain'	US-PGPUB; EPO; JPO;	15:30
Į			DERWENT;	
	2.470		IBM_TDB	
-	3470	gardner.inv.	USPAT; US-PGPUB;	2002/09/04
			EPO; JPO;	13.13
			DERWENT;	
1_	6	gardner.inv. and 'vertical transistor'	IBM_TDB USPAT;	2002/09/04
		and @ad<=20010323	US-PGPUB;	15:48
		· ·	EPO; JPO;	,
			DERWENT; IBM TDB	
_	4		USPAT;	2003/03/25
1		drain'	US-PGPUB;	14:24
			EPO; JPO; DERWENT;	
			IBM_TDB	
-	257	@ad<=20010323 and 'elevated source'	USPAT; US-PGPUB;	2002/09/04
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			DERWENT;	
_	37	@ad<=20010323 and 'epitaxial' with	IBM_TDB USPAT;	2003/06/24
	3,	'elevated source'	US-PGPUB;	14:23
			EPO; JPO;	
			DERWENT; IBM TDB	
-	1	"4728623".PN.	USPAT	2002/09/04
	1	"4739037" DN	IISDAT	16:31
_	1	"4738937".PN.	USPAT	16:31
-	1	"4918029".PN.	USPAT	2002/09/04
_	1	 "5004702".PN.	USPAT	16:31
-		J004/02 .FN.	OSEMI	16:31
-	1	"5030583".PN.	USPAT	2002/09/04
1_	1	"5032538".PN.	USPAT	16:31
		332230 .EN.	JULIA	16:31
	1	"5045494".PN.	USPAT	2002/09/04
	1	"5272109".PN.	USPAT	16:31 2002/09/04
				16:32
-	. 1	"5496750".PN.	USPAT	2002/09/04
_	1	"5378651".PN.	USPAT	16:38
	_			16:38
-	1	"5321306".PN.	USPAT	2002/09/04
	l		L	16:38

-	1	"5296388".PN.	USPAT	2002/09/04 16:38
-	1	"5250454".PN.	USPAT	2002/09/04
-	1	"5213991".PN.	USPAT	2002/09/04
- ,	1	"5079180".PN.	USPAT	2002/09/04
-	1	"5057899".PN.	USPAT	2002/09/04
-	1	"4966861".PN.	USPAT	2002/09/04
-	1	"4814841".PN.	USPAT	2002/09/04 16:48
-	1	"5057893".PN.	USPAT	2002/09/04 16:48
-	18	(("6096596") or ("6090691") or ("6057200") or ("6001697") or ("5998844") or ("5963822") or ("5945698") or ("5933738") or ("5863826")).PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/09/05 08:23
-	18	(("5831334") or ("5677573") or ("5641694") or ("5600161") or ("5497017") or ("5312768") or ("5156987") or ("5122476") or ("5087586")).PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/09/05 10:18
-	2	("5308782").PN.	USPAT; US-PGPUB; EPO; JPO;	2002/09/05 10:19
· -	2	("6319782").PN.	DERWENT; IBM_TDB USPAT;	2002/09/05
			US-PGPUB; EPO; JPO; DERWENT; IBM TDB	10:19
-	1731	((438/300) or (257/302) or (257/929) or (257/592)).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT;	2002/11/20 08:44
_	12	ri-seiko.in.	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2002/11/20 08:44
_	38	<pre>@ad<=20010323 and 'epitaxial' with 'elevated source'</pre>	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2002/11/20 09:33
_	263	@ad<=20010323 and 'elevated source'	IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2002/11/20 09:33
_	263	@ad<=20010323 and elevated adj1 source	DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2002/11/20 09:02
_	95	@ad<=20010323 and elevated adj1 drain	DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2002/11/20 09:02
- ,.	112	@ad<=20010323 and raised adj1 drain	DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/20 09:03

	200			T
-	229	@ad<=20010323 and raised adj1 source	USPAT;	2002/11/20
			US-PGPUB;	09:03
İ			EPO; JPO;	
			DERWENT; IBM TDB	
1_	0	@ad<=20010323 and 'epitaxial silicon	USPAT;	2002/11/20
		gate' with 'elevated source'	US-PGPUB;	09:38
		gate with elevated source	EPO; JPO;	05.50
•			DERWENT;	
			IBM TDB	
_	20	@ad<=20010323 and 'silicon gate' and	USPAT;	2002/11/20
		'elevated source'	US-PGPUB;	09:38
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	1
-	47	@ad<=20010323 and 'polysilicon gate' and	USPAT;	2003/03/25
		'elevated source'	US-PGPUB;	14:14
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	0	@ad<=20010323 and 'epitaxial polysilicon	USPAT;	2003/03/25
		gate' and 'elevated source'	US-PGPUB;	14:25
1.			EPO; JPO; DERWENT;	
			IBM TDB	
_	1	@ad<=20010323 and 'epitaxial polysilicon'	USPAT;	2002/11/20
		and 'elevated source'	US-PGPUB;	10:08
		and crevated bourse	EPO; JPO;	
			DERWENT;	
1			IBM TDB	
-	56	@ad<=20010323 and 'epitaxial polysilicon'	USPAT;	2002/11/21
Ì		• • • • • • • • • • • • • • • • • • •	US-PGPUB;	08:20
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	0	@ad<=20010323 and 'epitaxial polysilicon	USPAT;	2002/11/20
		gate'	US-PGPUB;	14:05
			EPO; JPO;	
}	'		DERWENT;	
	24	 @ad<=20010323 and 'epitaxial gate'	IBM_TDB USPAT;	2002/11/20
-	24	ead<=20010323 and replicantal gate	US-PGPUB;	14:05
		·	EPO; JPO;	14.05
1	1		DERWENT;	
	l		IBM TDB	
-	24	@ad<=20010323 and 'epitaxial gate'	USPAT;	2002/11/21
		· · · · · · · · · · · · · · · · · · ·	US-PGPUB;	08:30
			EPO; JPO;	
1			DERWENT;	
1			IBM_TDB	
-	560	@ad<=20010323 and polysilicon with	USPAT;	2002/11/20
	1	epitaxial with gate	US-PGPUB;	16:16
1	1		EPO; JPO;	,
			DERWENT;	
i _	2240	 @ad<=20010323 and 'multilayer' same	IBM_TDB USPAT;	2002/11/21
1	2348	dad<=20010323 and 'multilayer' same	USPAT; US-PGPUB;	2002/11/21 08:55
		yace	EPO; JPO;	*****
1		`	DERWENT;	
1			IBM TDB	
-	260	(@ad<=20010323 and 'multilayer' same	USPAT;	2002/11/20
		'gate') and 'epitaxial'	US-PGPUB;	16:18
1			EPO; JPO;	
1			DERWENT;	
1	[IBM_TDB	[
-	0	Cam:	USPAT;	2003/06/25
1		'epitaxial'	US-PGPUB;	08:33
			EPO; JPO;	
			DERWENT;	
L	l		IBM TDB	

-	1	@ad<=20010323 and epitaxial near grow near polysilicon	USPAT; US-PGPUB; EPO; JPO;	2002/11/21 08:20
			DERWENT; IBM_TDB	·
-	693	<pre>@ad<=20010323 and 'epitaxial silicon' same 'gate'</pre>	USPAT; US-PGPUB;	2002/11/21 08:32
			EPO; JPO; DERWENT; IBM TDB	
-	367	<pre>@ad<=20010323 and 'epitaxial silicon' with 'gate'</pre>	USPAT; US-PGPUB;	2002/11/21 08:41
			EPO; JPO; DERWENT;	
_	9	@ad<=20010323 and 'epitaxial silicon gate'	IBM_TDB USPAT; US-PGPUB;	2003/03/26 10:14
			EPO; JPO; DERWENT;	
_	1	@ad<=20010323 and 'multilayer silicon gate'	IBM_TDB USPAT; US-PGPUB;	2002/11/21 08:56
			EPO; JPO; DERWENT;	
- , .	1	("6534809").PN.	IBM_TDB USPAT; US-PGPUB;	2003/03/25
			EPO; JPO; DERWENT;	13.33
-	564	@ad<=20010323 and 'polysilicon gate' same 'epitaxial'	IBM_TDB USPAT; US-PGPUB;	2003/03/25
		epitaxiai	EPO; JPO; DERWENT;	14.10
_	390	(257/756).ccls and @ad<=20010323	IBM_TDB USPAT; US-PGPUB;	2003/06/24 14:43
			EPO; JPO; DERWENT;	14.45
_	214	@ad<=20010323 and 'floating gate' same 'epitaxial'	IBM_TDB USPAT; US-PGPUB;	2003/03/25
		CPICATAI	EPO; JPO; DERWENT;	
_	2141	<pre>@ad<=20010323 and 'elevated' same 'source' and 'drain'</pre>	IBM_TDB USPAT; US-PGPUB;	2003/03/25 14:28
			EPO; JPO; DERWENT;	
-	413	@ad<=20010323 and 'elevated' with 'source' with 'drain'	IBM_TDB USPAT; US-PGPUB;	2003/03/25
			EPO; JPO; DERWENT;	
-	6	<pre>@ad<=20010323 and 'epi silicon' and 'elevated' same 'source'</pre>	IBM_TDB USPAT; US-PGPUB;	2003/06/25
			EPO; JPO; DERWENT;	
-	1	"4074300".PN.	IBM_TDB USPAT	2003/03/25 14:37
-	32	<pre>@ad<=20010323 and 'gate stack' and 'elevated' same 'source'</pre>	USPAT; US-PGPUB;	2003/03/25 15:13
8			EPO; JPO; DERWENT; IBM_TDB	
-	8	(("4583105") or ("6083815") or ("5885877") or ("5986328")).PN.	USPĀT; US-PGPUB;	2003/03/25 15:39
			DERWENT; IBM_TDB	
-	8		IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	I .

-	2	("5198378").PN.	USPAT;	2003/03/25
	,		US-PGPUB;	15:39
			EPO; JPO;	
-			DERWENT;	
		,	IBM_TDB	
-	92	@ad<=20010323 and 'epi' and 'silicon	USPAT;	2003/03/26
		gate'	US-PGPUB;	11:54
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
_	9	@ad<=20010323 and 'epitaxial silicon	USPAT;	2003/03/26
		gate'	US-PGPUB;	11:10
		gacc	EPO; JPO;	11.10
			DERWENT;	
,	1	/!! (E 202 (2!! \ DM	IBM_TDB USPAT;	2003/03/26
-	l	("6528363").PN.	·	
		·	US-PGPUB;	11:10
			EPO; JPO;	İ
			DERWENT;	
			IBM_TDB	
_	7	@ad<=20010323 and 'conductor' same 'epi'	USPAT;	2003/03/26
		same 'polysilicon' same 'amorphous'	US-PGPUB;	14:31
			EPO; JPO;	
			DERWENT;	
}			IBM_TDB	
_	0	@ad<=20010323 and 'conductive' same 'epi'	USPAT;	2003/03/26
		same 'polysilicon' same 'amorphous'	US-PGPUB;	12:04
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
1_	3	("6335251").PN.	USPAT;	2003/03/26
		(0000Z0I).EN.	US-PGPUB;	14:34
1			EPO; JPO;	11:01
			DERWENT;	
	_	(#C020C41#) PV	IBM_TDB	2002/02/26
-	2	("6232641").PN.	USPAT;	2003/03/26
			US-PGPUB;	15:01
		,	EPO; JPO;	
			DERWENT;	
		·	IBM_TDB	
-	2	("6171910").PN.	USPAT;	2003/03/26
			US-PGPUB;	15:20
1	1		EPO; JPO;	
			DERWENT;	
			IBM_TDB	.
-	2	("6051473").PN.	USPĀT;	2003/03/26
]		US-PGPUB;	15:20
			EPO; JPO;	
1			DERWENT;	
			IBM TDB	·
-	8	@ad<=20010323 and 'epi silicon' and	USPAT;	2003/06/24
1	· · ·	'raised' same 'source'	US-PGPUB;	14:42
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
l _	9	@ad<=20010323 and 'epitaxial' adj1	USPAT;	2003/06/24
1		'silicon' adj1 'gate'	US-PGPUB;	14:36
	}	sificon adji gate		+ 3.50
			EPO; JPO;	
	1		DERWENT;	
ĺ	1	0.14.00010202 1 1 1 1.1	IBM_TDB	1 2002 /06 /04
-	24	@ad<=20010323 and 'epitaxial' adj1 'gate'	USPAT;	2003/06/24
			US-PGPUB;	14:36
			EPO; JPO;	
	1		DERWENT;	
			IBM_TDB]
-	11	@ad<=20010323 and 'epi silicon' and	USPAT;	2003/06/24
,	1	'raised' same 'source'	US-PGPUB;	14:42
			EPO; JPO;	
	1		DERWENT;	
	1		IBM TDB]
	<u> </u>	<u> </u>		·

	394	(257/756)11 0-14-20010222	IICDAM.	2002/06/25
_	394	(257/756).ccls and @ad<=20010323	USPAT; US-PGPUB;	2003/06/25 08:50
			EPO; JPO;	00.50
			DERWENT;	
			IBM_TDB	
-	600	438/300 and @ad<=20010323	USPAT;	2003/06/25
			US-PGPUB;	08:58
i		•	EPO; JPO;	
			DERWENT; IBM TDB	
_	2	("6534809").PN.	USPAT;	2003/06/25
	_	(0034003).IN.	US-PGPUB;	06:43
			EPO; JPO;	
			DERWENT;]
			IBM_TDB	
-	173	@ad<=20010323 and 'epitaxial' adj1	USPAT;	2004/03/18
		'silicon' and 'elevated' same 'source'	US-PGPUB;	13:32
			EPO; JPO;	
			DERWENT;	,
_	2	@ad<=20010323 and 'epitaxial' adj1	IBM_TDB USPAT;	2003/06/25
-		'silicon gate' and 'elevated' same	US-PGPUB;	06:46
		'source'	EPO; JPO;	
			DERWENT;	
			IBM TDB	
-	43	<pre>@ad<=20010323 and 'gate' with 'epitaxial'</pre>	USPAT;	2003/06/25
1		adj1 'silicon' and 'elevated' same	US-PGPUB;	07:35
		'source'	EPO; JPO;	
			DERWENT;	.
			IBM_TDB	0000 (05 (05
<u> </u>	17	@ad<=20010323 and 'transistor gate' with	USPAT;	2003/06/25
		'epitaxial' adj1 'silicon'	US-PGPUB;	07:45
			EPO; JPO; DERWENT;	
			IBM TDB	
_	143	<pre>@ad<=20010323 and 'transistor gate' with</pre>	USPAT;	2003/06/25
	2.10	'epitaxial'	US-PGPUB;	09:33
		•	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	238	<pre>@ad<=20010323 and 'epitaxial' adj2 'gate'</pre>	USPAT;	2003/06/25
			US-PGPUB;	08:08
			EPO; JPO;	
			DERWENT; IBM TDB	
_	2	@ad<=20010323 and 'stacked gate' with	USPAT;	2003/06/25
	2	'epitaxial'	US-PGPUB;	08:33
	·	- F =	EPO; JPO;	
			DERWENT;	
		•	IBM_TDB	
-	243	(438/657).ccls. and @ad<=20010323	USPAT;	2004/03/18
			US-PGPUB;	16:48
			EPO; JPO;	
			DERWENT;	,
_	225	(438/647).ccls. and @ad<=20010323	IBM_TDB USPAT;	2003/06/25
	223	1.50/ 04//.cozo. and Gad-20010323	US-PGPUB;	08:56
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	118	(257/385).ccls. and @ad<=20010323	USPĀT;	2003/06/25
			US-PGPUB;	08:56
			EPO; JPO;	
			DERWENT;	
1_	534	(257/382).ccls. and @ad<=20010323	IBM_TDB USPAT;	2003/06/25
-	334	\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\	US-PGPUB;	08:59
1			EPO; JPO;	33.33
1			DERWENT;	
			IBM TDB	
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	·			
-	225	(438/647).ccls. and @ad<=20010323	USPAT;	2003/06/25
			US-PGPUB;	08:57
			EPO; JPO;	
			DERWENT;	
_	313	(438/300).ccls. and @ad<=20010323	IBM_TDB USPAT;	2004/10/18
-	313	(438/300).CCIS. and ead<=20010323	US-PGPUB;	14:23
			EPO; JPO;	14.23
			DERWENT;	
		,	IBM TDB	ĺ
_	69	(257/381).ccls. and @ad<=20010323	USPAT;	2003/06/25
		(207,001,100107 and can't 10010020	US-PGPUB;	08:59
			EPO; JPO;	1
			DERWENT;	
			IBM TDB	
-	244	(257/756).ccls. and @ad<=20010323	USPAT;	2003/06/25
			US-PGPUB;	08:59
			EPO; JPO;	
			DERWENT;	
i			IBM_TDB	/ _ /
-	197	@ad<=20010323 and 'polysilicon gate' with	USPAT;	2003/06/25
i		'epitaxial'	US-PGPUB;	09:36
1			EPO; JPO;	
			DERWENT;	
1_	. 0	@ad<=20010323 and 'epitaxial silicon'	IBM_TDB USPAT;	2003/11/12
-	. •	with 'selected silicon'	US-PGPUB;	11:35
	ļ	MICH SETECTED STITCOH	EPO; JPO;	11.33
		-	DERWENT;	
	•		IBM TDB	
_	238	@ad<=20010323 and 'single' with 'poly'	USPAT;	2003/11/12
	250	with 'amorphous'	US-PGPUB;	14:09
			EPO; JPO;	
			DERWENT;	
1			IBM_TDB	
-	386	@ad<=20010323 and 'epitaxial silicon'	USPAT;	2003/11/12
		with 'gate'	US-PGPUB;	11:42
}			EPO; JPO;	1
			DERWENT;	
			IBM_TDB	
-	88	@ad<=20010323 and 'gate electrode' with	USPAT;	2003/11/12
	['epitaxial silicon'	US-PGPUB;	13:07
	1		EPO; JPO; DERWENT;	<u> </u>
	1		IBM TDB	
_	5	<pre>@ad<=20010323 and 'epitaxial' near 'gate'</pre>	USPAT;	2003/11/12
	1	near 'silicon'	US-PGPUB;	13:11
			EPO; JPO;	
			DERWENT;	
	1		IBM TDB	
-	68	<pre>@ad<=20010323 and 'epitaxial' near 'gate'</pre>	USPAT;	2003/11/12
	1		US-PGPUB;	13:19
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	14		USPAT;	2003/11/12
		near 'gate'	US-PGPUB;	13:19
			EPO; JPO;	
1	1		DERWENT;	
1		0-4-20010222 1 1 1 1 1	IBM_TDB	2002/11/12
ļ -	187	1 ·	USPAT;	2003/11/12
	1	near4 'gate'	US-PGPUB;	13:47
	1		EPO; JPO; DERWENT;	
1	1		IBM TDB	
_	138	@ad<=20010323 and 'epitaxial silicon'	USPAT;	2003/11/12
1		near3 'gate'	US-PGPUB;	13:20
1			EPO; JPO;	
1			DERWENT;	
1			IBM TDB	
			•	

	2	("6534809").PN.	USPAT;	2003/11/12
			US-PGPUB; EPO; JPO;	13:47
			DERWENT;	
			IBM_TDB	
-	428	@ad<=20010323 and 'schottky gate' and	USPAT;	2003/11/12
		'epitaxial'	US-PGPUB; EPO; JPO;	14:12
			DERWENT;	
			IBM TDB	
-	. 8	@ad<=20010323 and 'schottky gate' and	USPAT;	2003/11/12
		'epitaxial silicon'	US-PGPUB; EPO; JPO;	14:18
			DERWENT;	
			IBM TDB	
-	1971	@ad<=20010323 and 'epitaxial silicon'	USPAT;	2003/11/12
		nearl 'layers'	US-PGPUB;	14:34
			EPO; JPO; DERWENT;	
			IBM TDB	
-	13		USPAT;	2003/11/12
	•	near1 'layers' near1 'gate'	US-PGPUB;	14:34
			EPO; JPO; DERWENT;	
			IBM TDB	
-	65	@ad<=20010323 and 'epitaxial silicon'	USPAT;	2003/11/12
		near1 'layers' near2 'gate'	US-PGPUB;	15:11
			EPO; JPO; DERWENT;	
			IBM TDB	
_	2	("5110748").PN.	USPAT;	2003/11/12
			US-PGPUB;	15:37
	Ì		EPO; JPO; DERWENT;	•
İ			IBM TDB	
-	1	"3959045".PN.	USPĀT	2003/11/12
		#200F2001# PV	,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,	15:12
_	1	"3997381".PN.	USPAT	2003/11/12 15:12
_	1	"4292730".PN.	USPAT	2003/11/12
				15:13
-	1	"4888304".PN.	USPAT	2003/11/12 15:13
_	1	"4891329".PN.	USPAT	2003/11/12
	_			15:14
-	1	"4983251".PN.	USPAT	2003/11/12
_	1	"5006487".PN.	USPAT	15:14 2003/11/12
-	1	3000407 .FN.	OSTAL	15:15
-	1	"5006487".PN.	USPAT	2003/11/12
	_	#5012601# PW	TICDAE.	15:16
-	1	"5013681".PN.	USPAT	2003/11/12 15:17
_	0	("candelaria.in.").PN.	USPAT;	2003/11/12
			US-PGPUB;	15:38
		·	EPO; JPO; DERWENT;	
			IBM TDB	
-	0	("candelaria-jon.in.").PN.	USPAT;	2003/11/12
	1		US-PGPUB;	15:37
] .		EPO; JPO;	
	,		DERWENT; IBM TDB	
-	-0	("candelaria-jon-j.in.").PN.	USPAT;	2003/11/12
			US-PGPUB;	15:38
			EPO; JPO; DERWENT;	
			IBM TDB	
L		I		

_	0	("Candelaria-jon-j.in.").PN.	USPAT; US-PGPUB;	2003/11/12 15:39
			EPO; JPO; DERWENT;	
			IBM_TDB	
-	65	candelaria.in.	USPAT;	2003/11/12
			US-PGPUB;	15:38
			EPO; JPO;	
			DERWENT;	
	_		IBM_TDB	
-	6	Candelaria-jon-j.in.	USPAT;	2003/11/12
Į.			US-PGPUB;	15:39
1			EPO; JPO; DERWENT;	
			IBM TDB	
_	2	"20020137269"	USPAT;	2004/03/18
	_	20020137203	US-PGPUB;	09:22
			EPO; JPO;	33.22
			DERWENT;	
			IBM TDB	
-	2	"20020093054"	USPĀT;	2004/03/18
			US-PGPUB;	10:09
			EPO; JPO;	
			DERWENT;	
1		W000100101078	IBM_TDB	0004/02/20
-	2	"20010019137"	USPAT;	2004/03/18
			US-PGPUB;	10:11
ĺ			EPO; JPO; DERWENT;	
			IBM TDB	
_	. 2	("6630721").PN.	USPAT;	2004/03/18
	_	(333,121 / 1211	US-PGPUB;	10:13
		د	EPO; JPO;	
			DERWENT;	
	1		IBM_TDB	
-	2	("6433382").PN.	USPAT;	2004/03/18
			US-PGPUB;	10:26
			EPO; JPO;	, 1
			DERWENT;	
1_	1	"5739567".PN.	IBM_TDB USPAT	2004/03/18
1	1	3739307 .FN.	OSFAI	10:19
_	1	"5627395".PN.	USPAT	2004/03/18
1	_			10:34
-	2	("6150688").PN.	USPAT;	2004/03/18
1		·	US-PGPUB;	10:33
			EPO; JPO;	
1			DERWENT;	
1	_	(#C027202#\ PM	IBM_TDB	2004/02/10
-	2	("6037202").PN.	USPAT; US-PGPUB;	2004/03/18
			EPO; JPO;	10.51
		·	DERWENT;	
1			IBM TDB	
-	22	(("5994735") or ("5886382") or	USPAT;	2004/03/18
1		("5780327") or ("5612563") or ("5612230")	US-PGPUB;	10:49
		or ("5595920") or ("5578850") or	EPO; JPO;	
1		("5574299") or ("4447889") or ("5483094")	DERWENT;	
		or ("5460994")).PN.	IBM_TDB	0004/02/20
-	108	@ad<=20010323 and 'vertical' with	USPAT;	2004/03/18
		'transistor' same 'epitaxial silicon'	US-PGPUB;	13:34
		•	EPO; JPO; DERWENT;	
			IBM TDB	
_	47	@ad<=20010323 and 'vertical' with	USPAT;	2004/03/18
	'	'transistor' with 'epitaxial silicon'	US-PGPUB;	13:34
1			EPO; JPO;	
1		· ·	DERWENT;	
			IBM TDB	

	1400	(0.57 / 0.16) 1 0 4 (0.001 0.202	III DAM.	0004/10/10
-	1480	(257/316).ccls. and @ad<=20010323	USPAT;	2004/10/18
			US-PGPUB;	14:18
			EPO; JPO; DERWENT;	
			IBM TDB	
	474	(257/303).ccls. and @ad<=20010323	USPAT;	2004/10/18
ļ -	4/4	(25//303).CCIS. and @ad<=20010323	'	14:18
1			US-PGPUB;	14:10
			EPO; JPO;	
			DERWENT;	
	1 1 1	(257/929).ccls. and @ad<=20010323	IBM_TDB USPAT;	2004/10/19
-	155	(257/929).CCIS. and @ad<=20010323	US-PGPUB;	2004/10/18 14:23
			EPO; JPO;	14:23
-	İ		DERWENT;	
	. 51	/430/333\ and and 6ad = 30010333	IBM_TDB USPAT;	2004/10/18
-] 51	(438/222).ccls. and @ad<=20010323		
1			US-PGPUB;	14:31
			EPO; JPO;	}
1			DERWENT;	
	076	(257/269) gglg and Badz-20010222	IBM_TDB USPAT;	2004/10/18
] -	876	(257/368).ccls. and @ad<=20010323	· ·	14:27
1			US-PGPUB;	14:51
			EPO; JPO;	
			DERWENT; IBM TDB	ĺ
	40	(257/41).ccls. and @ad<=20010323	USPAT;	2004/03/18
-	42	(257/41).CCIS. and @ad<=20010323	US-PGPUB;	16:54
			· .	16:54
			EPO; JPO; DERWENT;	
			IBM TDB	·
	34	(257/44).ccls. and @ad<=20010323	USPAT;	2004/03/18
-	34	(257/44).CCIS. and ead(-20010525	US-PGPUB;	16:56
			EPO; JPO;	10.50
	1		DERWENT;	
		•	IBM TDB	
_	751	(257/288).ccls. and @ad<=20010323	USPAT;	2004/03/18
	'31	(237/2007:0013: and ead(~20010323	US-PGPUB;	16:57
			EPO; JPO;	
			DERWENT;]
	1		IBM TDB	
_	732	(257/592).ccls. and @ad<=20010323	USPAT;	2004/03/18
	""	, , , , , , , , , , , , , , , , , , , ,	US-PGPUB;	16:57
			EPO; JPO;	
			DERWENT;	
1			IBM TDB	
-	242	(438/350).ccls. and @ad<=20010323	USPAT;	2004/03/18
		• • • • • • • • • • • • • • • • • • • •	US-PGPUB;	17:00
			EPO; JPO;	
-			DERWENT;	
			IBM TDB	
-	2	("5888294").PN.	USPAT;	2004/03/18
	1	· · · · · ·	US-PGPUB;	17:01
	1		EPO; JPO;	
	†		DERWENT;	
	1		IBM_TDB	
-	2	"20010040292"	USPĀT;	2004/03/18
			US-PGPUB;	17:01
			EPO; JPO;	
			DERWENT;	
L			IBM TDB	